- #26/E

Docket No. 0756-1986

June 14 26/E

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Yasuhiko TAKEMURA

Serial No. 09/342,235

Filed: June 29, 1999

SEMICONDUCTOR DEVICE For:

HAVING AT LEAST FIRST AND

SECOND THIN FILM

TRANSISTORS

) Group Art Unit: 2814

) Examiner: Ahmed N. Sefer

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with The United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231, an February 24, 2003.

Volely M Stampy

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AMENDMENT

Honorable Commissioner for Patents

Washington, D.C. 20231

Sir:

In response to the Office Action dated October 23, 2002, please amend ove-identified application as follows:

ECLAIMS:

13. (Amended) A semiconductor device comprising: the above-identified application as follows:

IN THE CLAIMS:

a substrate having an insulating surface;

at least first and second semiconductor islands formed directly on said insulating surface wherein each of the semiconductor islands has a channel region and a pair of impurity regions;

a first and a second gate insulating film formed over said semiconductor island, respectively;